() IDT.

LOW-VOLTAGE 10-BIT BUS SWITCH

FEATURES:

- $5\Omega A/B$ bi-directional switch
- · Isolation under power-off conditions
- Over-voltage tolerant
- Latch-up performance exceeds 100mA
- Vcc = 2.3V 3.6V, Normal Range
- ESD > 2000V per MIL-STD-883, Method 3015;
 > 200V using machine model (C = 200pF, R = 0)
- Available in QSOP and TSSOP packages

APPLICATIONS:

• 3.3V High Speed Bus Switching and Bus Isolation

FUNCTIONAL BLOCK DIAGRAM

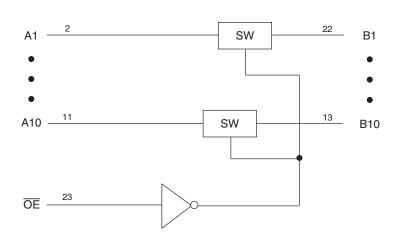
DESCRIPTION:

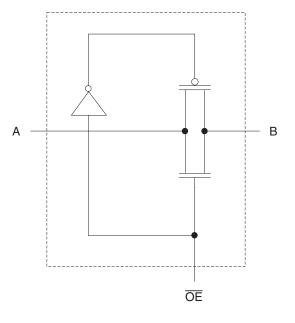
The CBTLV3861 provides ten bits of high-speed bus switching with low on-state resistance of the switch allowing connections to be made with minimal propagation delay.

The device is organized as one 10-bit bus switch. When output enable (\overline{OE}) is low, the 10-bit bus switch is on and port A is connected to port B. When \overline{OE} is high, the switch is open and a high-impedance state exists between the two ports.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to VCC through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

SIMPLIFIED SCHEMATIC, EACH SWITCH

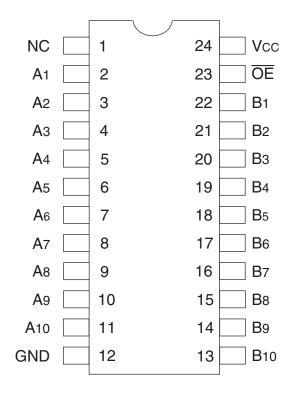




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OCTOBER 2012

PIN CONFIGURATION



QSOP / TSSOP TOP VIEW

INDUSTRIAL TEMPERATURE RANGE

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Description	Max	Unit
Vcc	SupplyVoltage Range	-0.5 to +4.6 V	
Vi	Input Voltage Range	-0.5 to +4.6	V
	Continuous Channel Current	128	mA
Ік	Input Clamp Current, VI/O < 0	-50	mA
Tstg	Storage Temperature	–65 to +150	°C

NOTE:

 Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

FUNCTION TABLE(1)

Input	
ŌĒ	Operation
L	A Port = B Port
Н	Disconnect

NOTE:

1. H = HIGH Voltage Level L = LOW Voltage Level

OPERATING CHARACTERISTICS, TA = 25^{\circ}C^{(1)}

Symbol	Parameter	Test Conditions	Min.	Max.	Unit
Vcc	Supply Voltage		2.3	3.6	V
Vih	High-Level Control Input Voltage	Vcc = 2.3V to 2.7V	1.7	—	V
		Vcc = 2.7V to 3.6V	2	—	
VIL	Low-Level Control Input Voltage	Vcc = 2.3V to 2.7V	—	0.7	V
		Vcc = 2.7V to 3.6V	—	0.8	
TA	Operating Free-Air Temperature		-40	85	°C
NOTE.					

NOTE:

1. All unused control inputs of the device must be held at Vcc or GND to ensure proper device operation.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified: Operating Conditions: TA = -40 °C to +85 °C

Symbol	Parameter	Te	Test Conditions		Typ. ⁽¹⁾	Max.	Unit
Vik	Control Inputs, Data I/O	Vcc = 3V, II = -18mA				-1.2	V
li	Control Inputs, Data I/O	Vcc = 3.6V, VI = Vcc or	GND	—	-	±1	μA
loz	Data I/O	Vcc = 3.6V, Vo = 0 or 3.	6V, switch disabled			5	μA
loff		Vcc = 0, Vi or Vo = 0 to	3.6V	—	-	50	μA
lcc		Vcc = 3.6V, Io = 0, VI =	Vcc = 3.6V, Io = 0, VI = Vcc or GND		-	10	μA
$\Delta ICC^{(2)}$	Control Inputs	Vcc = 3.6V, one input at	Vcc = 3.6V, one input at 3V, other inputs at Vcc or GND		- 1	300	μA
С	Control Inputs	Vi = 3V or 0	VI = 3V or 0		4	_	pF
CIO(OFF)		Vo = 3V or 0, OE = Vcc	$Vo = 3V \text{ or } 0, \overline{OE} = Vcc$		6	_	pF
	Vcc = 2.3V	VI = 0	Io = 64mA	- 1	5	8	
	Typ. at Vcc = 2.5V		lo = 24mA	_	5	8	
Ron ⁽³⁾		VI = 1.7V	Io = 15mA	-	27	40	Ω
		VI = 0	Io = 64mA	-	5	7	
	Vcc = 3V		lo = 24mA	- 1	5	7	1
		VI = 2.4V	Io = 15mA	<u> </u>	10	15	1

NOTES:

1. Typical values are at Vcc = 3.3V, +25°C ambient.

2. The increase in supply current is attributable to each current that is at the specified voltage level rather than Vcc or GND.

3. This is measured by the voltage drop between the A and B terminals at the indicated current through the switch.

SWITCHING CHARACTERISTICS

		$Vcc = 2.5V \pm 0.2V$		Vcc = 3.3V ± 0.3V		
Symbol	Parameter	Min.	Max.	Min.	Max.	Unit
t PD ⁽¹⁾	Propagation Delay	-	0.15	—	0.25	ns
	A to B or B to A					
ten	Output Enable Time	1	4.5	1	4.2	ns
	OE to A or B					
tois	OutputDisableTime	1	5	1	5	ns
	OE to A or B					

NOTE:

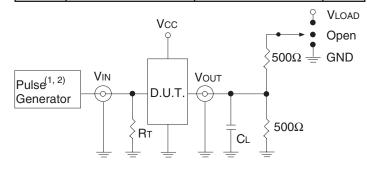
1. The propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the specified load capacitance driven by an ideal voltage source (zero output impedance).

IDT74CBTLV3861 LOW-VOLTAGE 10-BIT BUS SWITCH

TEST CIRCUITS AND WAVEFORMS

TEST CONDITIONS

Symbol	Vcc ⁽¹⁾ =3.3V±0.3V	Vcc ⁽²⁾ =2.5V±0.2V	Unit
VLOAD	6	2 x Vcc	V
Vih	3	Vcc	V
Vτ	1.5	Vcc / 2	V
Vlz	300	150	mV
VHZ	300	150	mV
CL	50	30	рF



Test Circuits for All Outputs

DEFINITIONS:

CL = Load capacitance: includes jig and probe capacitance.

RT = Termination resistance: should be equal to ZOUT of the Pulse Generator.

NOTES:

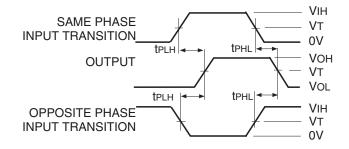
1. Pulse Generator for All Pulses: Rate \leq 1.0MHz; tF \leq 2.5ns; tR \leq 2.5ns.

2. Pulse Generator for All Pulses: Rate \leq 1.0MHz; tr \leq 2ns; tr \leq 2.5ns.

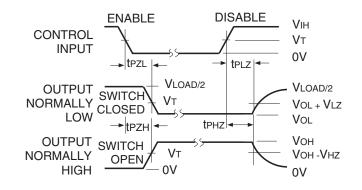
SWITCH POSITION

Test	Switch
tPLZ/tPZL	Vload
tpнz/tpzн	GND
ted	Open

INDUSTRIAL TEMPERATURE RANGE

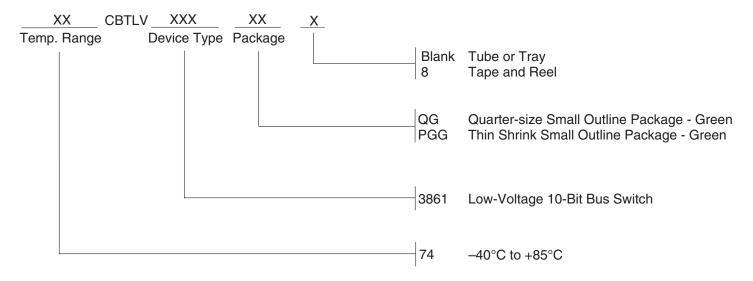






Enable and Disable Times

ORDERING INFORMATION



Datasheet Document History

10/02/12 Pg. 5

Updated the ordering information by removing the "IDT" notation also by removing non RoHS part and by adding Tape and Reel information.



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Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

IDT (Integrated Device Technology): 74CBTLV3861PGG 74CBTLV3861QG 74CBTLV3861PGG8 74CBTLV3861QG8